Измерение сопротивления тонкой пленки на поверхности электрода

<u>M. A. Vorotyntsev^{1,2,3}</u>, D. V. Konev³, M. Skompska⁴

¹ ICMUB-UMR 6302 CNRS, Universite de Bourgogne, Dijon, France
² M. V. Lomonosov Moscow State University, Russia
³ Institute for Problems of Chemical Physics, Chernogolovka, Russia
⁴ University of Warsaw, Poland

mivo2010@yandex.com, mv@elch.chem.msu.ru, mv@u-bourgogne.fr

In situ measurements of specific conductivity of films on electrode surface

- Specific conductivity: function of potential
- Impedance problems:
- 1. Special equipment
- 2. Interpretation (electrode/film resistance!)
- 3. Non-uniform electric field distribution



ľ,

Principal in situ method: microband electrodes

- Various constructions (no commercial supply!):
- 2 metal plates separated by a thin insulating layer One can clean by polishing





- Film above electrodes and gaps.
- Current between them via film
- Film resistance $\Delta U / I = R_f$ Film conductivity: $R_f = G / \kappa$

Film resistance: $\Delta U / I = R_f$ Film conductivity: $R_f = G / \kappa$

Problem of two electrodes configuration: contribution of electrode/film resistance



- 4 microband electrodes: separation of R_f and $R_{m/f}$
- U.Lange, V.M.Mirsky, Analyt. Chim. Acta, 2011, 687,105
- Another problem: Is the film uniform? Which thickness? One opinion: only R_f Another opinion: $G = L_g / A_f$
- Gap width: 5-100 µm Film thickness? Microband height?



Our study: film growth on microband electrodes



Series of pot-static depositions various PPy film thicknesses



Disk + single microband Large scale AFM device Contact mode





Similar profiles near edges of microband and macrodisk Slightly different film thicknesses in central areas

Single microband: film cross-section



Growth rates in normal and tangent directions are comparable



Disk: AFM images

Increase of film thickness:

Greater elements Higher roughness

Impossible to estimate G, i.e. film conductivity κ



Film conductivity: novel method M. A. Vorotyntsev, D. V. Konev, Electrochim. Acta, 2011, 56, 9105

Standard 3-electrode cell with static disc electrode



Solution: 3D distribution. Thin film: 1D distribution

Film conductivity: novel method Electrochim. Acta, 2011, 56, 9105

Potential step:

- non-stationary potential/current distributions
- Primary (short-time) potential/current distributions:
- 1) no concentration changes, 2) no changes at interfaces
- Only induced fluxes of mobile charges in solution & film
- $\begin{array}{ll} \Delta \Phi = 0 & \text{at } z > 0 \text{ (solution)} \\ \mathbf{i} = -\kappa_s \, \nabla \Phi & \text{at } z > 0 \text{ (solution)} \\ \mathbf{i}_z \cong \kappa_f \left(\mathsf{V} \Phi_o \right) / \mathsf{L}_f \text{ (thin film)} \\ \mathsf{V} : \text{ amplitude of potential step} \end{array}$



Electrochim. Acta, 2011, 56, 9105

- Total short-time resistance: $R_{tot} = V/I_o$ Nonadditive contributions of solution (R_s) and film (R_f) resistances Analytical formulas:
- $R_{tot}(R_s, R_f) \& R_f(R_s, R_{tot})$



If R_{tot} is measured for a set of electrode potentials, $R_{tot}(E)$, one can determine $R_{f}(E)$

Specific conductivity of the film, $\kappa_f(E)$:

$$R_f = G_f / \kappa_f, \qquad G_f = L_f / A_f, \quad A_f = \pi r_o^2$$

Conclusions

- For the first time: study of polymer film growth on nonuniform surfaces (single- and double-bands)
- Contrary to a widely-used hypothesis: no preferential film propagation along the surface
- To measure the interband current, i.e. film resistance the film thickness should be about a half of the interband gap, i.e. micrometer range, while the local and global film morphologies become non-uniform

Novel "potential-step method for disk electrode" to measure absolute values of in situ specific conductivity $\kappa_{f}(E)$ of film on electrode surface, i.e. in contact with solution under electrode potential control. Advantages:

- Standard electrochemical cell,
- Measuring device = potentiostat (short-time signals),
- Normal-size (about mm) disk electrode, no need of micro/nanoelectrodes or larger-size (cm) electrodes,
- Standard film deposition procedure,
- Thin films (from a few tens of nm),
- Electronic or ionic or mixed (electron-ion) conductivity,
- Non-destructive type of measurement

Limitations of potential step method:

1) $R_f << R_s$, 2) too low conductivity (displacement current)

Combination of microband and potential step methods: matching dependences resistance vs potential. Another method to determine film conductivity, $\kappa(E)$